MMBF2201N, NVF2201N

Power MOSFET 300 mAmps, 20 Volts

N-Channel SC-70/SOT-323

These miniature surface mount MOSFETs low $R_{DS(on)}$ assure minimal power loss and conserve energy, making these devices ideal for use in small power management circuitry. Typical applications are dc-dc converters, power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

Features

- Low R_{DS(on)} Provides Higher Efficiency and Extends Battery Life
- Miniature SC-70/SOT-323 Surface Mount Package Saves Board Space
- NVF Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable*
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	20	Vdc
Gate-to-Source Voltage - Continuous	V _{GS}	± 20	Vdc
$ \begin{array}{l} \text{Drain Current} \\ - \text{ Continuous @ } T_A = 25^\circ\text{C} \\ - \text{ Continuous @ } T_A = 70^\circ\text{C} \\ - \text{ Pulsed Drain Current (} t_p \leq 10 \ \mu\text{s}) \end{array} $	I _D ID IDM	300 240 750	mAdc
Total Power Dissipation @ T _A = 25°C (Note 1) Derate above 25°C	P _D	150 1.2	mW mW/°C
Operating and Storage Temperature Range	T _J , T _{stg}	– 55 to 150	°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	833	°C/W
Maximum Lead Temperature for Soldering Purposes, for 10 seconds	ΤL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 Mounted on G10/FR4 glass epoxy board using minimum recommended footprint.

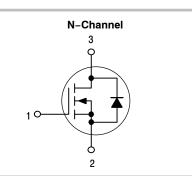


ON Semiconductor®

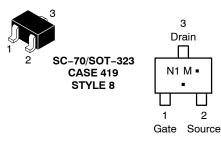
http://onsemi.com

300 mAMPS, 20 VOLTS

 $R_{DS(on)} = 1 \Omega$



MARKING DIAGRAM AND PIN ASSIGNMENT



N1 = Device Code

= Pb–Free Package

(Note: Microdot may be in either location) *Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]		
MMBF2201NT1G	SOT–323 (Pb–Free)	3000 / Tape & Reel		
NVF2201NT1G*	SOT–323 (Pb–Free)	3000 / Tape & Reel		

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

1

M = Date Code*

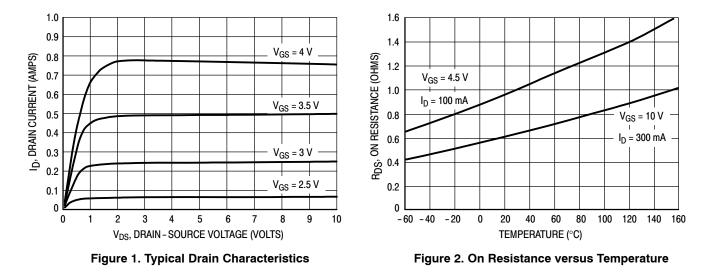
MMBF2201N, NVF2201N

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Ch	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage ($V_{GS} = 0$ Vdc, $I_D = 10 \ \mu$ A)	V _{(BR)DSS}	20	-	-	Vdc	
Zero Gate Voltage Drain Current (V_{DS} = 16 Vdc, V_{GS} = 0 Vdc) (V_{DS} = 16 Vdc, V_{GS} = 0 Vdc, T_J					1.0 10	μAdc
Gate-Body Leakage Current (V _{GS}	I _{GSS}	-	-	±100	nAdc	
ON CHARACTERISTICS (Note 2)		•		•	•	
Gate Threshold Voltage ($V_{DS} = V_{GS}$, $I_D = 250 \ \mu Adc$)	V _{GS(th)}	1.0	1.7	2.4	Vdc	
$\begin{array}{l} \mbox{Static Drain-to-Source On-Resista} \\ (V_{GS} = 10 \mbox{ Vdc}, \mbox{ I}_{D} = 300 \mbox{ mAdc}) \\ (V_{GS} = 4.5 \mbox{ Vdc}, \mbox{ I}_{D} = 100 \mbox{ mAdc}) \end{array}$	r _{DS(on)}		0.75 1.0	1.0 1.4	Ω	
Forward Transconductance (V _{DS} =	9 FS	-	450	-	mMhos	
DYNAMIC CHARACTERISTICS						
Input Capacitance	(V _{DS} = 5.0 V)	C _{iss}	-	45	-	pF
Output Capacitance	(V _{DS} = 5.0 V)	C _{oss}	-	25	-	
Transfer Capacitance	(V _{DG} = 5.0 V)	C _{rss}	-	5.0	-	
SWITCHING CHARACTERISTICS	(Note 3)	-				
Turn-On Delay Time		t _{d(on)}	-	2.5	-	ns
Rise Time	(V _{DD} = 15 Vdc, I _D = 300 mAdc,	tr	-	2.5	-	
Turn-Off Delay Time	$R_L = 50 \Omega$)	t _{d(off)}	-	15	-	-
Fall Time		t _f	-	0.8	-	
Gate Charge (See Figure 5)	QT	-	1400	-	рС	
SOURCE-DRAIN DIODE CHARAG	TERISTICS					
Continuous Current	ا _S	-	-	0.3	Α	
Pulsed Current	I _{SM}	-	-	0.75		
Forward Voltage (Note 3)	V _{SD}	-	0.85	_	V	

2. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%.

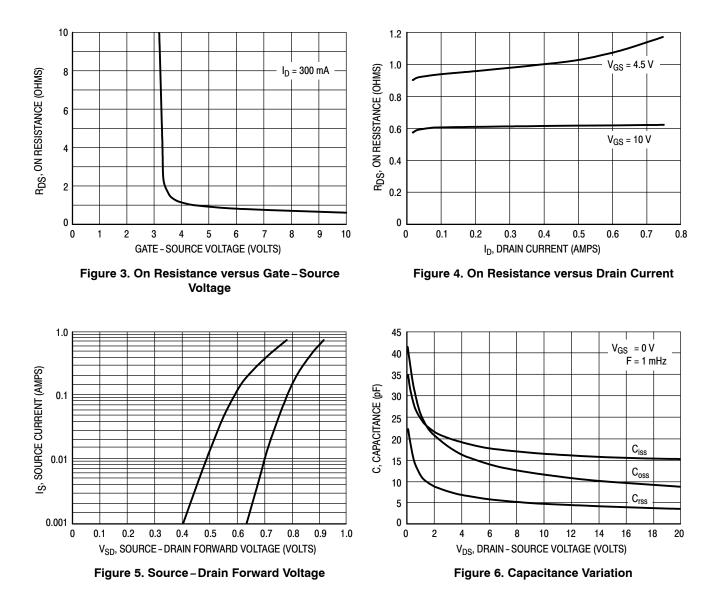
3. Switching characteristics are independent of operating junction temperature.



TYPICAL CHARACTERISTICS

MMBF2201N, NVF2201N

TYPICAL CHARACTERISTICS



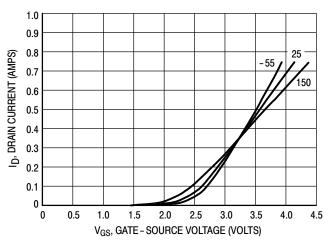
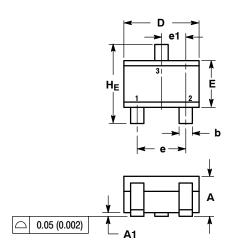


Figure 7. Transfer Characteristics

PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04

ISSUE N



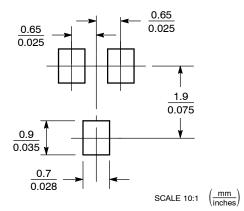
NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
с	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
е	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095



SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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